TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

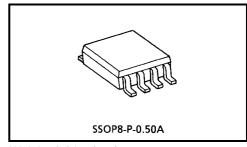
# TC7WB126FK

#### **Dual Bus Switch**

The TC7WB126FK is a low on-resistance, high-speed CMOS dual-bit bus switch. This bus switch allows the connections or disconnections to be made with minimal propagation delay while maintaining Low power dissipation which is the feature of CMOS

When output enable (OE) is at High level, the switch is on; when at Low level, the switch is off.

All inputs are equipped with protector circuits to protect the device from static discharge.

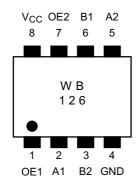


Weight: 0.01 g (typ.)

#### **Features**

- Operating voltage:  $V_{CC} = 4.5 \sim 5.5 \text{ V}$
- High speed operation:  $t_{pd} = 0.25 \text{ ns (max)}$
- Ultra-low on resistance:  $RON = 5 \Omega$  (typ.)
- Electro-static discharge (ESD) performance:  $\pm 200$  V or more (EIAJ)  $\pm 2000$  V or more (MIL)
- TTL level input (control input)
- · Package: US8

#### Pin Assignment (top view)



980910EBA1

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## **Truth Table**

**TOSHIBA** 

Inputs	Function
OE	Tunction
L	Disconnect
Н	A port = B port

## **System Diagram**



## **Maximum Ratings**

Characteristics	Symbol	Rating	Unit	
Power supply range	V <sub>CC</sub>	-0.5~7.0	V	
DC input voltage	VIN	-0.5~7.0	V	
DC switch voltage	Vs	-0.5~7.0	V	
Input diode current	I <sub>IK</sub>	-50	mA	
Continuous channel current	IS	128	mA	
Power dissipation	PD	200	mW	
DC V <sub>CC</sub> /GND current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA	
Storage temperature	T <sub>stg</sub>	-65~150	°C	

## **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	4.5~5.5	V
Input voltage	V <sub>IN</sub>	0~5.5	V
Switch voltage	Vs	0~5.5	V
Operating temperature	T <sub>opr</sub>	-40~85	°C
Input rise and fall time	dt/dv	0~10	ns/V



#### **Electrical Characteristics**

#### DC Characteristics ( $Ta = -40 \sim 85$ °C)

Characte	rictics	Symbol	Test Condition -			Min	Тур.	Max	Unit
Characte	ristics	Syllibol	Test Condi	uon	V <sub>CC</sub> (V)	IVIIII	(Note1)	IVIAX	Offic
Input voltage	"H" level	V <sub>IH</sub>	_		4.5~5.5	2.0	_		V
input voitage	"L" level	V <sub>IL</sub>	_		4.5~5.5			8.0	V
Input leakage cu	rrent	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5 V		5.5		_	±1.0	μΑ
Off-state leakage (switch off)	current	I <sub>SZ</sub>	A, B = 0~5.5 V, OE = GND		0~5.5	_		±1.0	μА
ON registance			V <sub>IS</sub> = 0 V	$I_{IS} = 30 \text{ mA}$	4.5	_	5	7	
ON resistance	(Note2)	R <sub>ON</sub>		I <sub>IS</sub> = 64 mA	4.5	_	5	7	Ω
(Note2)		$V_{IS} = 2.4 \text{ V}, I_{IS} = 15 \text{ mA}$		4.5	_	10	15		
Quiescent supply	current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND I <sub>OUT</sub> = 0		5.5			10	mA
		$\Delta I_{CC}$	V <sub>IN</sub> = 3.4 V (one input)		5.5	_	_	2.5	mA

Note1: Typical values are at  $V_{CC} = 5 \text{ V}$  and  $T_0 = 25^{\circ}\text{C}$ .

Note2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

### AC Characteristics ( $Ta = -40 \sim 85$ °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time (bus to bus)	t <sub>pLH</sub>	Figure 1, Figure 2 (Note3)	4.5	—	0.25	ns
Output enable time	t <sub>pZL</sub>	Figure 1, Figure 3	4.5	—	4.0	ns
Output disable time	t <sub>pLZ</sub>	Figure 1, Figure 3	4.5	_	5.5	ns

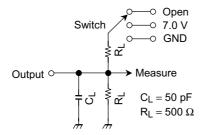
Note3: The propagation delay time is calculated by the RC (on-resistance and load capacitance) time constant.

#### **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Тур.	Unit
Control pin input capacitance	C <sub>IN</sub>		(Note4)	5.0	3	pF
Switch terminal capacitance	C <sub>I/O</sub>	OE = GND	(Note4)	5.0	10	pF

Note4: This item is guaranteed by design.

#### **AC Test Circuit**



Parameter	Switch	
t <sub>pLH</sub> , t <sub>pHL</sub>	Open	
$t_{pLZ}, t_{pZL}$	7.0 V	
t <sub>pHZ</sub> , t <sub>pZH</sub>	Open	

Figure 1

## **AC Waveform**

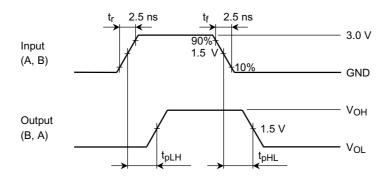


Figure 2  $t_{pLH}$ ,  $t_{pHL}$ 

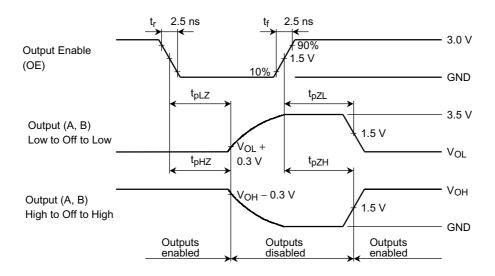
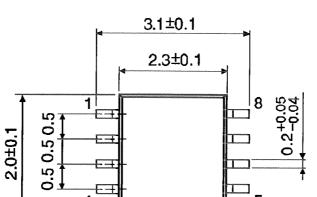


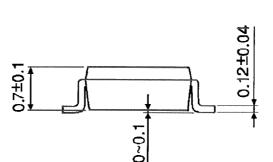
Figure 3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$ 

Unit: mm

# **Package Dimensions**

SSOP8-P-0.50A





Weight: 0.01 g (typ.)